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# 74HC166; 74HCT166

# 8-bit parallel-in/serial out shift register Rev. 3 — 11 September 2013

**Product data sheet** 

#### 1. **General description**

The 74HC166; 74HCT166 is an 8-bit serial or parallel-in/serial-out shift register. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and a serial output (Q7). When the parallel enable input (PE) is LOW, the data from D0 to D7 is loaded into the shift register on the next LOW-to-HIGH transition of the clock input (CP). When PE is HIGH, data enters the register serially at DS with each LOW-to-HIGH transition of CP. When the clock enable input (CE) is LOW data is shifted on the LOW-to-HIGH transitions of CP. A HIGH on CE disables the CP input. Inputs include clamp diodes which enable the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

#### Features and benefits 2.

- Synchronous parallel-to-serial applications
- Synchronous serial input for easy expansion
- Complies with JEDEC standard no. 7A
- Input levels:
  - ◆ For 74HC166: CMOS level
  - For 74HCT166: TTL level
- ESD protection:
  - ◆ HBM JESD22-A114E exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

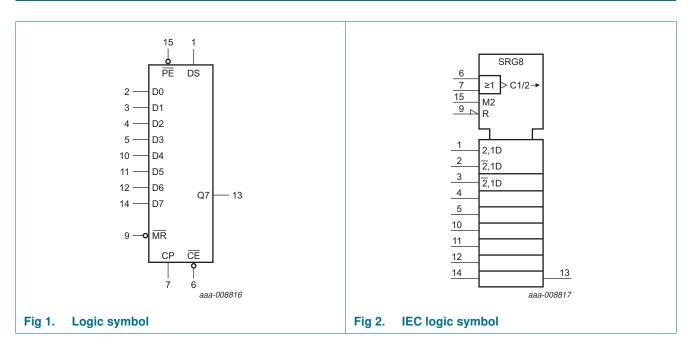
#### Ordering information 3.

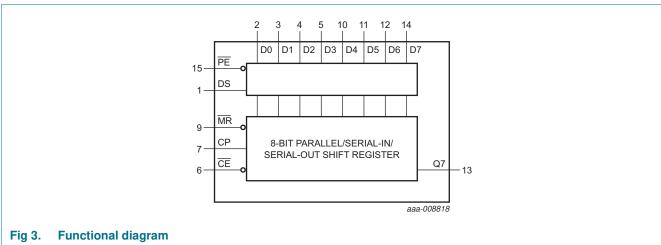
Table 1. **Ordering information** 

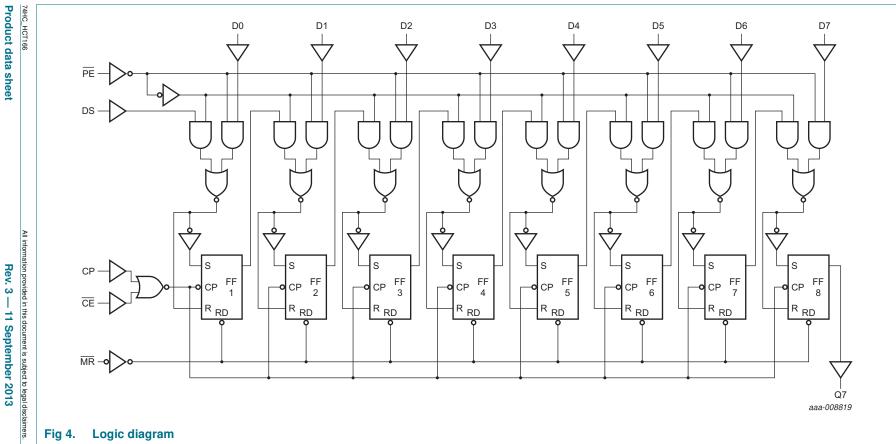
Type number	Package			
	Temperature range	Name	Description	Version
74HC166N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
74HCT166N				
74HC166D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT166D				
74HC166DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width	SOT338-1
74HCT166DB			5.3 mm	
74HC166PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1



## 4. Functional diagram

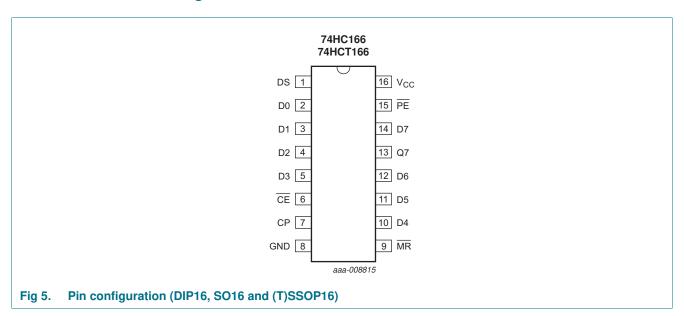






## 5. Pinning information

### 5.1 Pinning



## 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
DS	1	serial data input
D0 to D7	2, 3, 4, 5, 10, 11, 12, 14	parallel data inputs
CE	6	clock enable input (active LOW)
СР	7	clock input (LOW-to-HIGH edge-triggered)
GND	8	ground (0 V)
MR	9	asynchronous master reset (active LOW)
Q7	13	serial output from the last stage
PE	15	parallel enable input (active LOW)
V <sub>CC</sub>	16	positive supply voltage

## 6. Functional description

Table 3. Function table[1]

Operating modes	Inputs			Qn regi	Qn registers			
	PE	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7
parallel load	I	I	<b>↑</b>	Χ	I	L	L to L	L
	I	I	<b>↑</b>	Χ	h	Н	H to H	Н
serial shift	h	I	<b>↑</b>	l	Χ	L	q0 to q5	q6
	h	I	<b>↑</b>	h	Χ	Н	q0 to q5	q6
hold "do nothing"	Χ	Н	Χ	Χ	Χ	q0	q1 to q6	q7

#### [1] H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

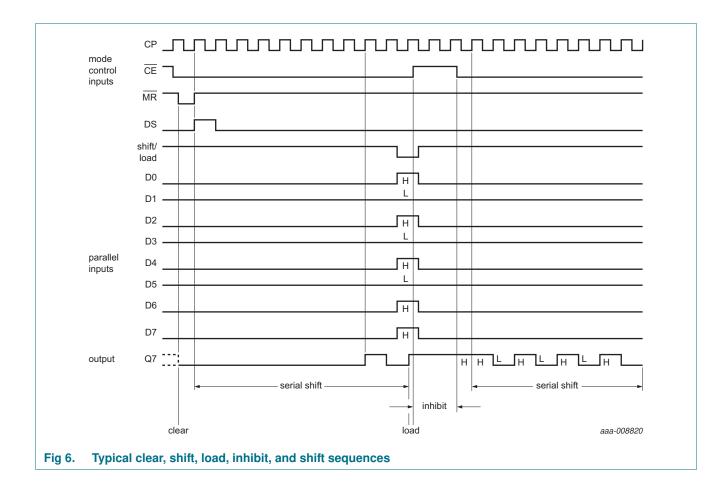
L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

q = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

X = don't care;

↑ = LOW-to-HIGH clock transition.



## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{I}<-0.5\ V$ or $V_{I}>V_{CC}$ + $0.5\ V$	<u>[1]</u> -	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I <sub>CC</sub>	supply current		-	50	mA
$I_{GND}$	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$			
		DIP16 package	[2] -	750	mW
		SO16 package	[3] _	500	mW
		(T)SSOP16 package	<u>[4]</u> _	500	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>[2]</sup> Ptot derates linearly with 12 mW/K above 70 °C.

<sup>[3]</sup> Ptot derates linearly with 8 mW/K above 70 °C.

<sup>[4]</sup> Ptot derates linearly with 5.5 mW/K above 60 °C.

## 8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC166		7	4HCT16	6	Unit	
			Min	Тур	Max	Min	Тур	Max	
$V_{CC}$	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	$V_{CC}$	0	-	$V_{CC}$	V
Vo	output voltage		0	-	$V_{CC}$	0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 \text{ V}$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V

## 9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	6				'	1			1	
V <sub>IH</sub>	HIGH-level	$V_{CC} = 2.0 \text{ V}$	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 \text{ V}$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	3.2	-	4.2	-	4.2	-	V
$V_{IL}$	LOW-level	$V_{CC} = 2.0 \text{ V}$	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 \text{ V}$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.8	-	1.8	-	1.8	V
$V_{OH}$	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = -20 \mu A$ ; $V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
$V_{OL}$	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I <sub>CC</sub>	supply current	$V_{I}$ = $V_{CC}$ or GND; $I_{O}$ = 0 A; $V_{CC}$ = 6.0 V	-	-	8.0	-	80	-	160	μΑ

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	to +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	66									
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	2.0	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	8.0	-	0.8	-	0.8	V
$V_{OH}$	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = -20 \mu A$	4.4	4.5	-	4.4	-	4.4	-	٧
		$I_{O} = -4.0 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	٧
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 5.2 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	٧
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$	-	-	±0.1	-	±1	-	±1	μА
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 4.5 \text{ V}$	-	-	8.0	-	80	-	160	μА
Δl <sub>CC</sub>	additional supply current	per input pin; $\begin{split} &V_I = V_{CC} - 2.1 \text{ V;} \\ &\text{other inputs at } V_{CC} \text{ or GND;} \\ &V_{CC} = 4.5 \text{ V to } 5.5 \text{ V} \end{split}$								
		Dn and DS inputs	-	35	126	-	157.5	-	171.5	μΑ
		CP and CE inputs	-	80	288	-	360	-	392	μΑ
		MR input	-	40	144	-	180	-	196	μΑ
		PE input	-	60	216	-	270	-	294	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

## 10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V);  $t_r = t_f = 6$  ns:  $C_L = 50$  pF unless otherwise specified; for test circuit, see <u>Figure 10</u>

Symbol	Parameter	Conditions			25 °C	;	–40 °C t	o +85 °C	–40 °C to	+125 °C	Unit
			I	Min	Тур	Max	Min	Max	Min	Max	
74HC16	6		·								
t <sub>pd</sub>	propagation	CP to Q7; see Figure 7	[1]								
	delay	$V_{CC} = 2.0 \text{ V}$		-	50	150	-	190	-	225	ns
		$V_{CC} = 4.5 \text{ V}$		-	18	30	-	38	-	45	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	15	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	14	26	-	33	-	38	ns
		MR to Q7; see Figure 8									
		$V_{CC} = 2.0 \text{ V}$		-	47	160	-	200	-	240	ns
		$V_{CC} = 4.5 \text{ V}$		-	17	32	-	40	-	48	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	14	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	14	27	-	34	-	41	ns
t <sub>t</sub>	transition	output; see Figure 7	[2]								
	time	$V_{CC} = 2.0 \text{ V}$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 \text{ V}$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}$		-	6	13	-	16	-	19	ns
t <sub>w</sub> pı	pulse width	CP input HIGH or LOW; see Figure 7									
		$V_{CC} = 2.0 \text{ V}$		80	17	-	100	-	120	-	ns
		$V_{CC} = 4.5 \text{ V}$		16	6	-	20	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}$		14	5	-	17	-	20	-	ns
		MR input LOW; see Figure 8									
		$V_{CC} = 2.0 \text{ V}$		100	25	-	125	-	150	-	ns
		$V_{CC} = 4.5 \text{ V}$		20	9	-	25	-	30	-	ns
		$V_{CC} = 6.0 \text{ V}$		17	7	-	21	-	26	-	ns
t <sub>rec</sub>	recovery time	MR to CP; see Figure 8									
		$V_{CC} = 2.0 \text{ V}$		0	-19	-	0	-	0	-	ns
		$V_{CC} = 4.5 \text{ V}$		0	-7	-	0	-	0	-	ns
		$V_{CC} = 6.0 \text{ V}$		0	-6	-	0	-	0	-	ns
t <sub>su</sub>	set-up time	Dn, CE to CP; see Figure 9									
		$V_{CC} = 2.0 \text{ V}$		80	14	-	100	-	120	-	ns
		$V_{CC} = 4.5 \text{ V}$		16	5	-	20	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}$		14	4	-	17	-	20	-	ns
		PE to CP; see Figure 9									
		$V_{CC} = 2.0 \text{ V}$		100	33	-	125	-	150	-	ns
		$V_{CC} = 4.5 \text{ V}$		20	12	-	25	-	30	-	ns
		$V_{CC} = 6.0 \text{ V}$		17	10	-	21	-	26	-	ns

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 Table 7.
 Dynamic characteristics ...continued

GND (ground = 0 V);  $t_r = t_f = 6$  ns:  $C_L = 50$  pF unless otherwise specified; for test circuit, see <u>Figure 10</u>

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			N	/lin	Тур	Max	Min	Max	Min	Max	
t <sub>h</sub>	hold time	Dn, $\overline{\text{CE}}$ to CP; see Figure 9					1	'			•
		$V_{CC} = 2.0 \text{ V}$		2	-8	-	2	-	2	-	ns
		$V_{CC} = 4.5 \text{ V}$		2	-3	-	2	-	2	-	ns
		$V_{CC} = 6.0 \text{ V}$		2	-2	-	2	-	2	-	ns
		PE to CP; see Figure 9									
		$V_{CC} = 2.0 \text{ V}$		0	-28	-	0	-	0	-	ns
		$V_{CC} = 4.5 \text{ V}$		0	-10	-	0	-	0	-	ns
		$V_{CC} = 6.0 \text{ V}$		0	-8	-	0	-	0	-	ns
f <sub>max</sub>	maximum	CP input; see Figure 7									
	frequency	V <sub>CC</sub> = 2.0 V		6	19	-	4.8	-	4	-	MH
		$V_{CC} = 4.5 \text{ V}$	(	30	57	-	24	-	20	-	MH
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	63	-	-	-	-	-	MH
		$V_{CC} = 6.0 \text{ V}$	(	35	68	-	28	-	24	-	МН
$C_{PD}$	power dissipation capacitance	per package; $V_I = GND$ to $V_{CC}$	[3]	-	41	-	-	-	-	-	pF
74HCT16	66										
t <sub>pd</sub>	propagation delay	CP to Q7; see Figure 7	[1]								
	delay	V <sub>CC</sub> = 4.5 V		-	23	40	-	50	-	60	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	20	-	-	-	-	-	ns
		MR to Q7; see Figure 8									
		$V_{CC} = 4.5 \text{ V}$		-	22	40	-	50	-	60	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	19	-	-	-	-	-	ns
t <sub>t</sub>	transition	output; see Figure 7	[2]								
	time	$V_{CC} = 4.5 \text{ V}$		-	7	15	-	19	-	22	ns
t <sub>W</sub>	pulse width	CP input HIGH or LOW; see Figure 7									
		$V_{CC} = 4.5 \text{ V}$	2	20	9	-	25	-	30	-	ns
		MR input LOW; see Figure 8									
		$V_{CC} = 4.5 V$	2	25	11	-	31	-	38	-	ns
t <sub>rec</sub>	recovery time	MR to CP; see Figure 8									
		$V_{CC} = 4.5 V$		0	-7	-	0	-	0	-	ns
t <sub>su</sub>	set-up time	Dn, CE to CP; see Figure 9									
		$V_{CC} = 4.5 \text{ V}$		16	8	-	20	-	24	-	ns
		PE to CP; see Figure 9									
		V <sub>CC</sub> = 4.5 V	(	30	15	-	38	-	45	-	ns
t <sub>h</sub>	hold time	Dn, CE to CP; see Figure 9									
		$V_{CC} = 4.5 \text{ V}$		0	-3	-	0	-	0	-	ns
		PE to CP; see Figure 9									
		V <sub>CC</sub> = 4.5 V		0	-13	-	0	-	0	-	ns

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 Table 7.
 Dynamic characteristics ...continued

GND (ground = 0 V);  $t_r = t_f = 6$  ns:  $C_L = 50$  pF unless otherwise specified; for test circuit, see Figure 10

Symbol	Parameter	Conditions		25 °C		–40 °C to	+85 °C	-40 °C to	+125 °C	Unit	
				Min	Тур	Max	Min	Max	Min	Max	
f <sub>max</sub>	maximum	CP input; see Figure 7									
	frequency	$V_{CC} = 4.5 \text{ V}$		25	45	-	20	-	17	-	MHz
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	50	-	-	-	-	-	MHz
$C_{PD}$	power dissipation capacitance	per package; $V_I = GND$ to $V_{CC}$	[3]	-	41	-	-	-	-	-	pF

- [1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .
- [2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .
- [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

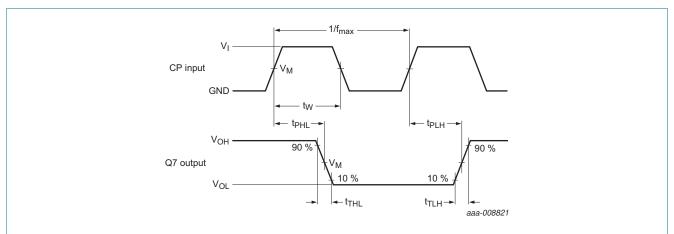
f<sub>o</sub> = output frequency in MHz;

 $\Sigma (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs};$ 

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V.

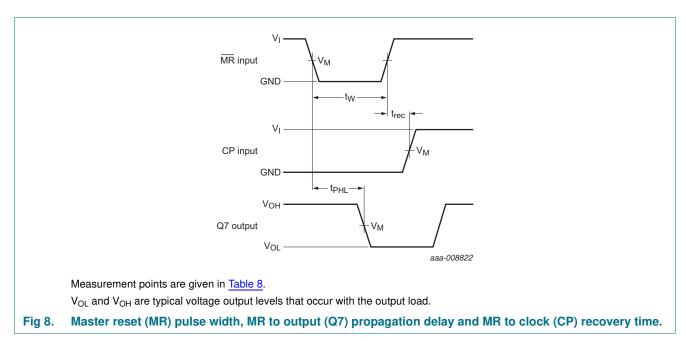
#### 11. Waveforms



Measurement points are given in Table 8.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

Fig 7. Clock (CP) to output (Q7) propagation delays, pulse width, output transition times and maximum frequency



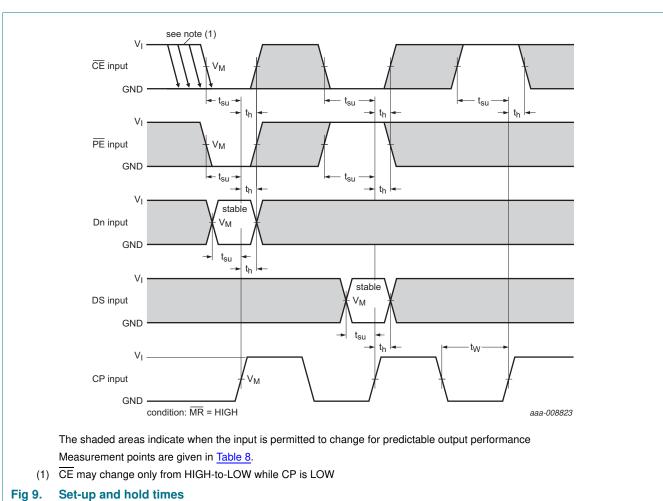
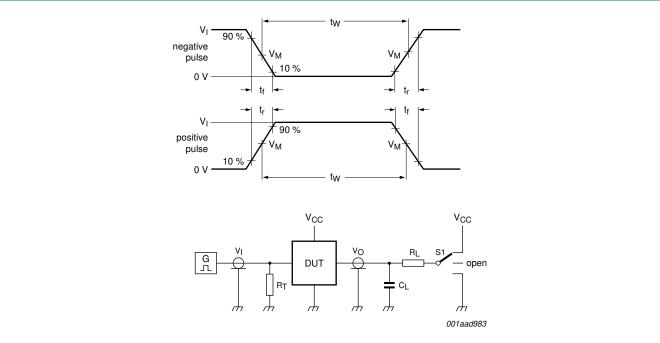


Table 8. Measurement points

Туре	Input	Input				
	VI	V <sub>M</sub>	V <sub>M</sub>			
74HC166	V <sub>CC</sub>	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>			
74HCT166	3 V	1.3 V	1.3 V			



Test data is given in Table 10.

Definitions for test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_{l}$  = Load resistance.

S1 = Test selection switch

Fig 10. Test circuit for measuring switching times

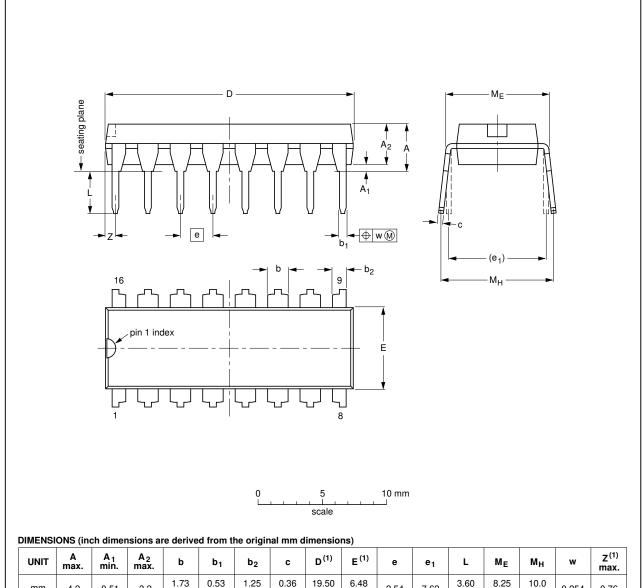
Table 9. Test data

Туре	Input		Load		S1 position
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub>	t <sub>PHL</sub> , t <sub>PLH</sub>
74HC166	$V_{CC}$	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT166	3 V	6 ns	15 pF, 50 pF	1 kΩ	open

## 12. Package outline

#### DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT38-4						<del>95-01-14</del> 03-02-13	

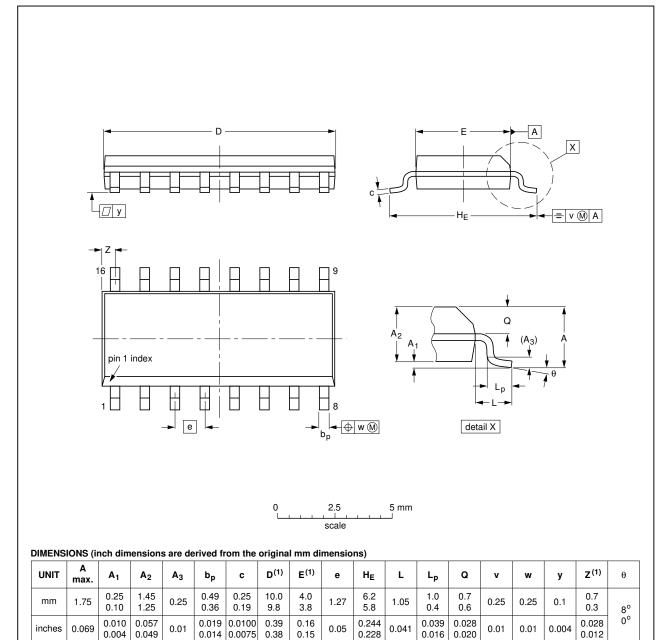
Fig 11. Package outline SOT38-4 (DIP16)

74HC\_HCT166

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#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

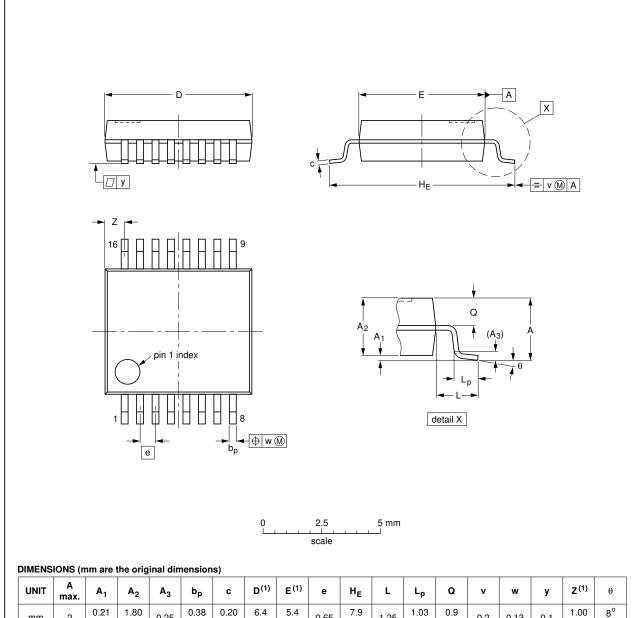
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19	

Fig 12. Package outline SOT109-1 (SO16)

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#### SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



-							-,												
	UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
	mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

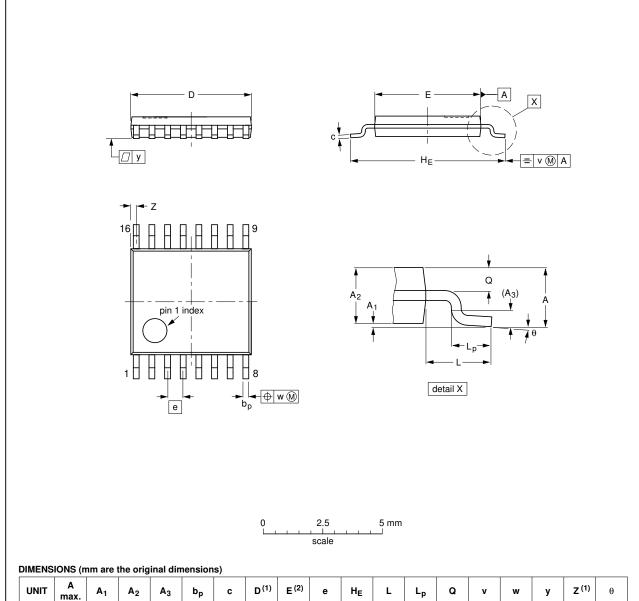
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT338-1		MO-150				<del>99-12-27</del> 03-02-19

Fig 13. Package outline SOT338-1 (SSOP16)

74HC\_HCT166

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E (2)	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18	

Fig 14. Package outline SOT403-1 (TSSOP16)

74HC\_HCT166

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## 13. Abbreviations

#### Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

## 14. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT166_3	20130911	Product data sheet	-	74HC_HCT166_CNV_2
Modifications:	guidelines of	of this data sheet has been red f NXP Semiconductors. have been adapted to the new		·
	ū	added, see Section 9 "Static cl		по арргорнато.
74HC_HCT166_CNV_2	December 1990	Product specification	-	-

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#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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